Att. No.1

**ORDER DESCRIPTION**

1. **Object of the contract**

The subject of the order is the supply of organometallic compounds in specialized containers (bubbler), listed below by name and quantity needed:

1. Dimethylcadmium (Electronic-grade), DMCd, container 2” 200g
2. Diisopropyltelluride (Electronic-grade), DIPTe, container 3” 400g
3. Diisopropyltelluride (Electronic-grade), DIPTe, container 2” 200g
4. **The scope of the subject of the contract**

A detailed description of the subject of the contract is provided in section 5 of this document. The offer should also include packaging and freight costs suitable for organometallic compounds and specialized containers.

1. **Criterion**

Offers will be evaluated according to a point scale with a maximum number of points of 100.

|  |  |  |
| --- | --- | --- |
| Criterion | Maximum number of points S | Method of awarding points |
| Net Price (P) | 100 | S x Pmin/Pi |

Where:

* Pi – net price of goods with delivery - for the given offer
* Pmin - the minimum net price for the ordered goods from all offers submitted
* S – number of points

The final score will be calculated by adding up the partial components and then rounded to two decimal places. (rounded from "5" up).

1. **Deadline for completing the order**

Up to 8 weeks from the date of order.

The date of completion of the subject of the contract is understood as the delivery of the subject of the contract to the headquarters of the Ordering Party in accordance with the offer. The Ordering Party requires application of the DAP Incoterms 2020 principle. According to the DAP (delivery at place) principle, the supply is considered to be completed at the time of delivery of the goods to the place indicated by the Ordering Party.

1. **Parameters**

|  |  |  |
| --- | --- | --- |
| Product name | Parametrer | Specification |
| Dimethylcadmium | GRADE | Electronic |
| Metal purity, %: | > 99,9999 |
| Metal impurities (ICP-OES) (unit: PPM): Aluminium (Al), Arsenic (As),Chromium (Cr), Copper (Cu), Gallium (Ga), Germanium (Ge), Indium (In), Iron (Fe), Lead (Pb), Magnesium (Mg), Manganese (Mn), Phosphorus (P), Selenium (Se), Silicon (Si), Sulfur (S), Tellurium (Te), Tin (Sn) | < 0,1 |
| Metal impurities: Mercury (Hg) | < 0,01 |
| Diisopropyltelluride | GRADE | Electronic |
| Metal purity, %: | > 99,9999 |
| Metal impurities (ICP-OES) (unit: PPM): Aluminium (Al), Antimony (Sb), Arsenic (As), Bismuth (Bi), Chromium (Cr), Copper (Cu), Gallium (Ga), Germanium (Ge), Indium (In), Iron (Fe), Lead (Pb), Magnesium (Mg), Manganese (Mn), Phosphorus (P), Selenium (Se), Silicon (Si), Sulfur (S), Tellurium (Te), Tin (Sn), Zinc (Zn) | < 0,01 |
| Metal impurities:  Cadmium (Cd), Mercury (Hg). | < 0,001 |